OF NOTION 1449APTO
OF MATION DISCLOSURE
OF EMENT BY APPLICANT
AS MELTY SHOOTS AS PROCESSALY) **Application Number** 10/728451 December 5, 2003 Filing Date **First Named Inventor** Scheuerlein, Roy 2815 Richards Unknown **Group Art Unit** Unknown **Examiner Name** Attorney Docket No: MA-112 Sheet 1 of 1

•			US PATENT	T DOCUMENTS			
Examiner Initial *	Cite No	USP Document Number	Publication Date	Name of Patentee or Applicant of cited Document	Class	Subclass	Filing Date If Appropriate
	<b>AT</b>	10/035078		Scheueriein et al.			18/31/2002
	A2	V10/611248		Cleeves			06/30/2003
~~~	А3	5835396	11/10/1998	Zhang			
مالارم	A4	6034882	03/07/2000	Johnson et al.	Tj.		
1-21-	A5	6185121	02/06/2001	O'Neill	1:		
Non	A6	US20020079553A1	06/27/2002	Cleeves	17	1	

F	DREIGN PATENT DOCUMENTS			
Examiner Cite Foreign Document No No	Publication Date  Name of Patentee or Applicant of cited  Document	Class	Subclass	T³

1	OTHER DOCUMENTS NON PATENT LITERATURE DOCUMENTS						
Exemine Initials*		include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-lesue number(s), publisher, city and/or country where published.	Ť²				
405~	A7	SCHEUERLEIN, ROY.E., et al., "A 10ns Read and Write Non-Volatile Memory Array Using a Magnetic Tunnel Junction and FET Switch in each Cell", 2000 IEEE International Solid-State Circuits Conference: ISSCC 2000, Feb 8, 2000: Emerging Memory and Device Technologies/Paper TA 7.2, (2/8/2000), 128-129					